

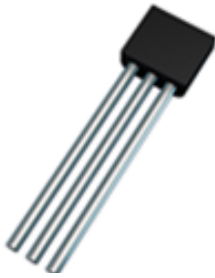
NPN SILICON PLANAR MEDIUM POWER TRANSISTOR

Features

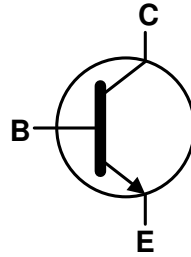
- $BV_{CEO} > 100V$ (ZTX453)
- $I_{CM} = 2A$ Peak Pulse Current
- $I_C = 1A$ High Continuous Current
- $P_D = 1W$ Power Dissipation
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**

Mechanical Data

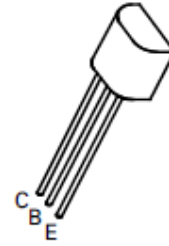
- Case: E-Line
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 ^{Ⓔ3}
- Weight: 159mg (Approximate)



E-Line



Device Symbol



Top View
Pin-Out

Ordering Information (Note 4)

Part Number	Compliance	Marking	Quantity
ZTX453	Standard	ZTX 453	4000 Bulk
ZTX453STZ	Standard	ZTX 453	2000 Taped

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

Marking Information



ZTX 453 = Product Type Marking Code

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CB0}	120	V
Collector-Emitter Voltage	V _{CEO}	100	V
Emitter-Base Voltage	V _{EBO}	5	V
Collector Current	I _C	1	A
Peak Collector Current	I _{CM}	2	A
Peak Dissipation at T _A = +25°C	P _D	1	W

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

ESD Ratings (Note 6)

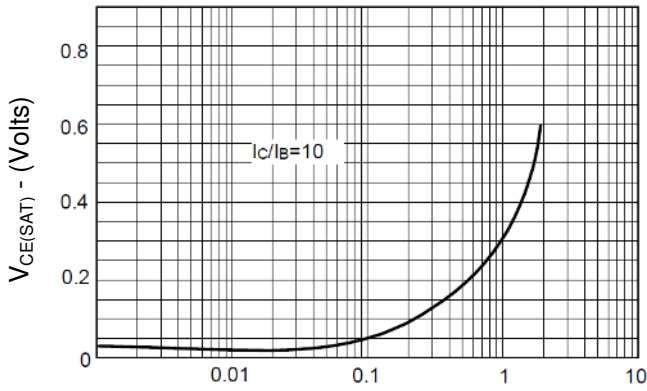
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	8,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic (Note 5)	Symbol	Min	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CB0}	120	—	V	I _C = 100μA, I _B = 0
Collector-Emitter Breakdown Voltage	BV _{CEO}	100	—	V	I _C = 10mA, I _B = 0
Emitter-Base Breakdown Voltage	BV _{EBO}	5	—	V	I _E = 100μA, I _C = 0
DC Current Gain	h _{FE}	40	200	—	V _{CE} = 10V, I _C = 150mA, V _{CE} = 10V, I _C = 1A
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	—	0.7	V	I _C = 150mA, I _B = 15mA
Base-Emitter Saturation Voltage	V _{BE(SAT)}	—	1.3	V	I _C = 150mA, I _B = 15mA
Collector-Cutoff Current	I _{CB0}	—	0.1	μA	V _{CB} = 100V
Emitter-Cutoff Current	I _{EBO}	—	0.1	μA	V _{EB} = 4V
Gain Bandwidth Product	f _T	150	—	MHz	V _{CE} = 10V, I _C = 50mA, f = 100MHz
Collector-Base Capacitance	C _{CB0}	—	3.0	pF	V _{CB} = 10V, f = 1MHz
Output Capacitance	C _{OBO}	—	15	pF	V _{CB} = 10V, f = 1MHz

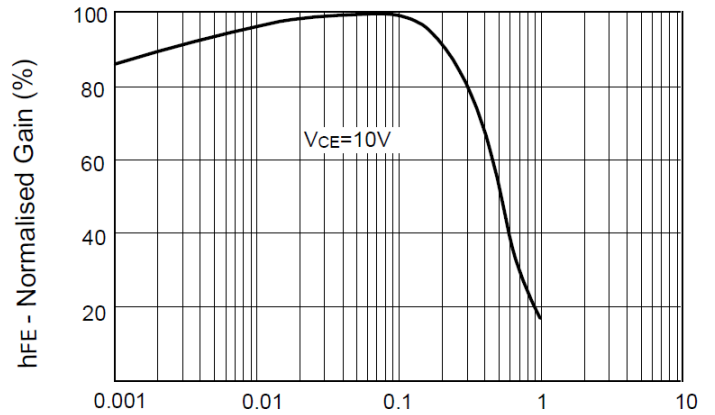
Notes: 5. Short duration pulse test used to minimize self-heating effect.
6. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

Typical Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)



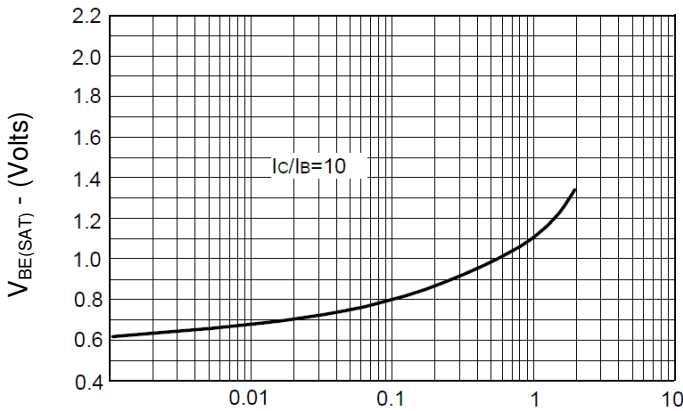
I_C - Collector Current (Amps)

$V_{CE(SAT)} \ v \ I_C$



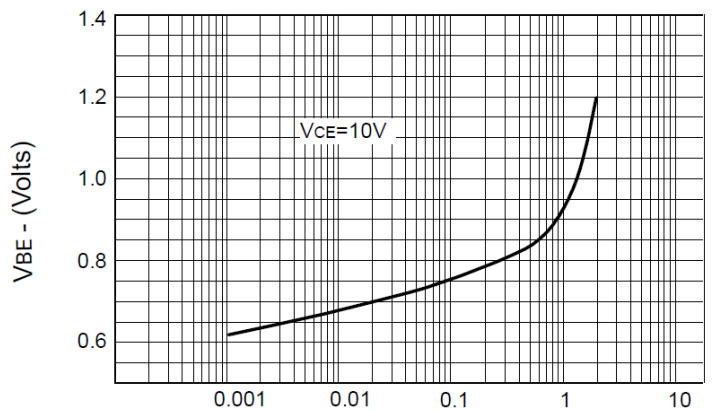
I_C - Collector Current (Amps)

$hFE \ v \ I_C$



I_C - Collector Current (Amps)

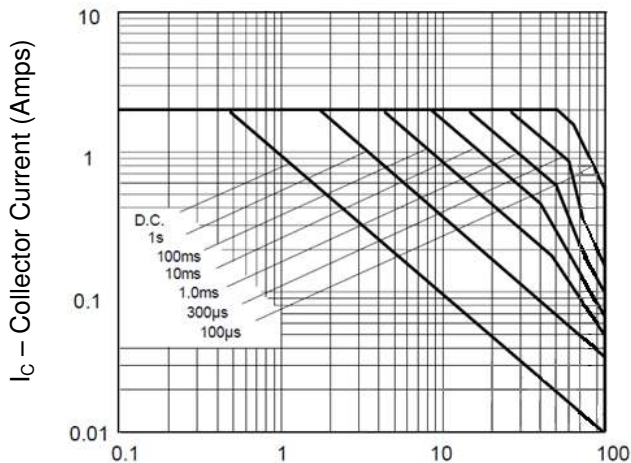
$V_{BE(SAT)} \ v \ I_C$



I_C - Collector Current (Amps)

$V_{BE(ON)} \ v \ I_C$

Single Pulse Test at $T_A = +25^\circ\text{C}$

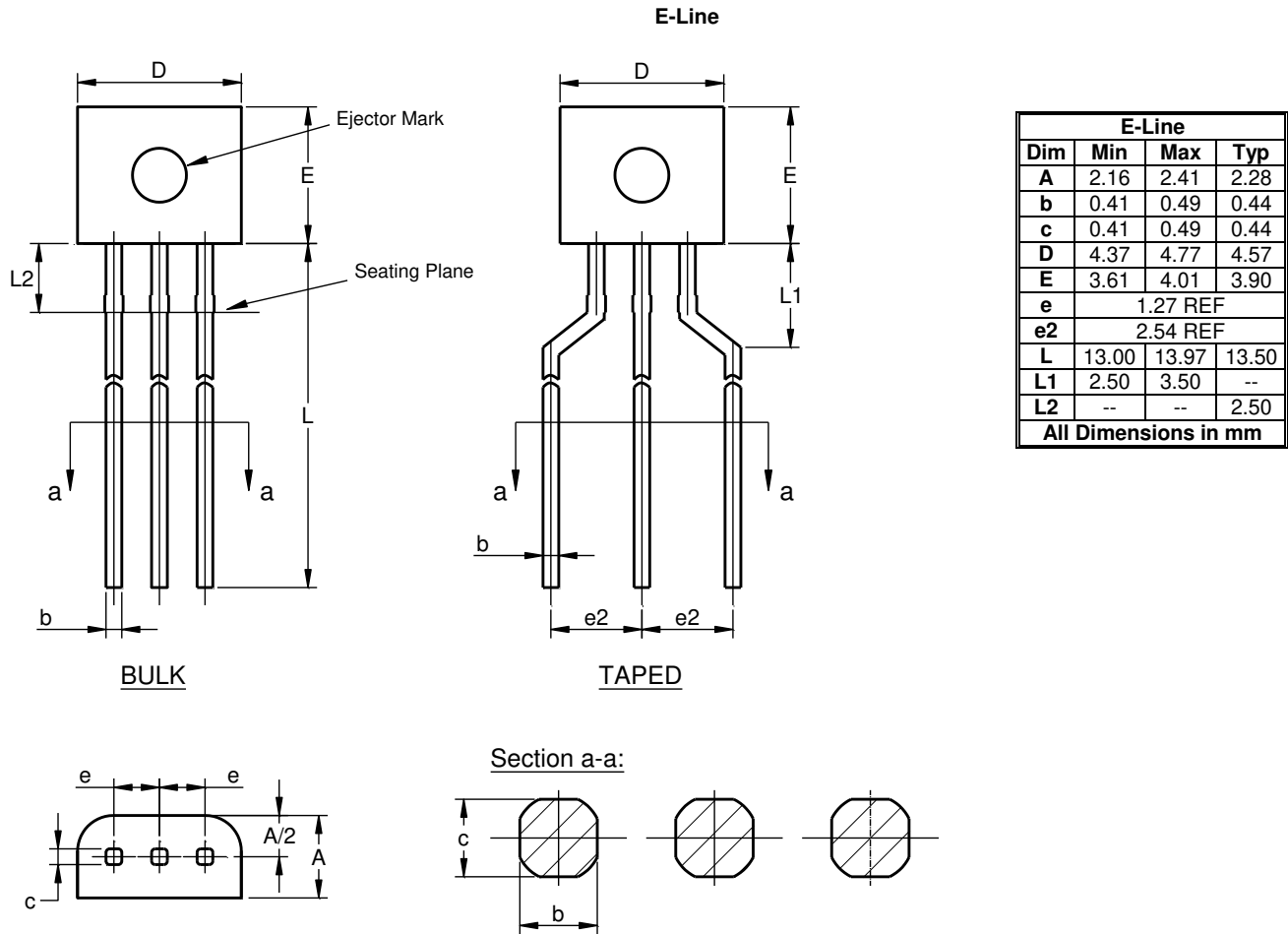


V_{CE} - Collector Voltage (Volts)

Safe Operating Area

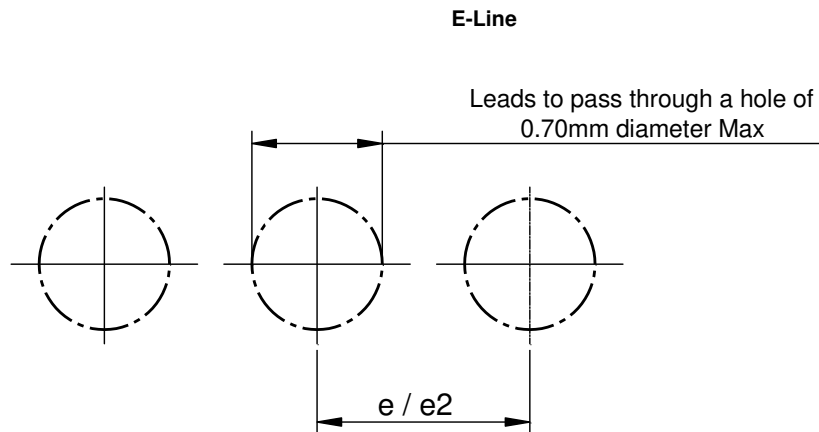
Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.



Suggested Pad Hole

Please see <http://www.diodes.com/package-outlines.html> for the latest version.



IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

A. Life support devices or systems are devices or systems which:

1. are intended to implant into the body, or
2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.

B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2016, Diodes Incorporated

www.diodes.com